

MMBTA06W, SMMBTA06W,

Driver Transistor

NPN Silicon

Features

- Moisture Sensitivity Level: 1
- ESD Rating:
 - ◆ Human Body Model – 4 kV
 - ◆ Machine Model – 400 V
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	80	Vdc
Collector–Base Voltage	V_{CBO}	80	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector Current – Continuous	I_C	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board $T_A = 25^\circ\text{C}$	P_D	460	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	272	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR–4 Board, 1 oz. Cu, 100 mm².

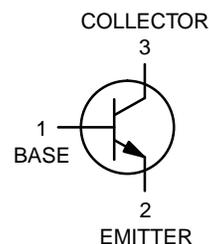


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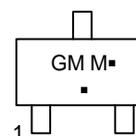
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SC–70
CASE 419
STYLE 3



MARKING DIAGRAM



GM = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MMBTA06WT1G	SC–70 (Pb–Free)	3,000 / Tape & Reel
SMMBTA06WT1G	SC–70 (Pb–Free)	3,000 / Tape & Reel
SMMBTA06WT3G	SC–70 (Pb–Free)	10,000 / Tape & Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MMBTA06W, SMMBTA06W,

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mA, I _B = 0)	V _{(BR)CEO}	80	–	Vdc
Emitter–Base Breakdown Voltage (I _E = 100 μA, I _C = 0)	V _{(BR)EBO}	4.0	–	Vdc
Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0)	I _{CES}	–	0.1	μA
Collector Cutoff Current (V _{CB} = 80 Vdc, I _E = 0)	I _{CBO}	–	0.1	μA

ON CHARACTERISTICS

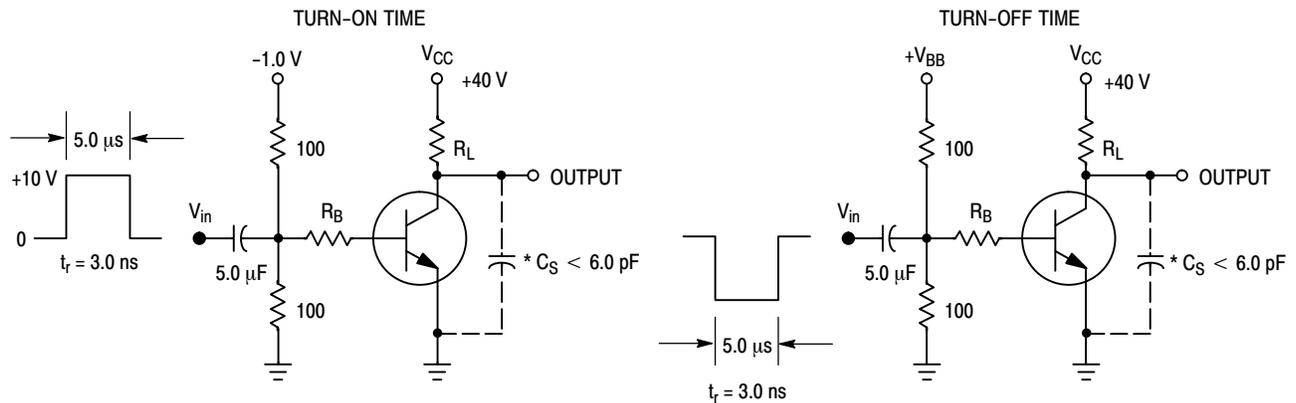
DC Current Gain (I _C = 10 mA, V _{CE} = 1.0 Vdc) (I _C = 100 mA, V _{CE} = 1.0 Vdc)	h _{FE}	100 100	– –	–
Collector–Emitter Saturation Voltage (I _C = 100 mA, I _B = 10 mA)	V _{CE(sat)}	–	0.25	Vdc
Base–Emitter On Voltage (I _C = 100 mA, V _{CE} = 1.0 Vdc)	V _{BE(on)}	–	1.2	Vdc

SMALL–SIGNAL CHARACTERISTICS

Current–Gain – Bandwidth Product (Note 2) (I _C = 10 mA, V _{CE} = 2.0 V, f = 100 MHz)	f _T	100	–	MHz
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
2. f_T is defined as the frequency at which |h_{fe}| extrapolates to unity.



*Total Shunt Capacitance of Test Jig and Connectors
For PNP Test Circuits, Reverse All Voltage Polarities

Figure 1. Switching Time Test Circuits

MMBTA06W, SMMBTA06W,

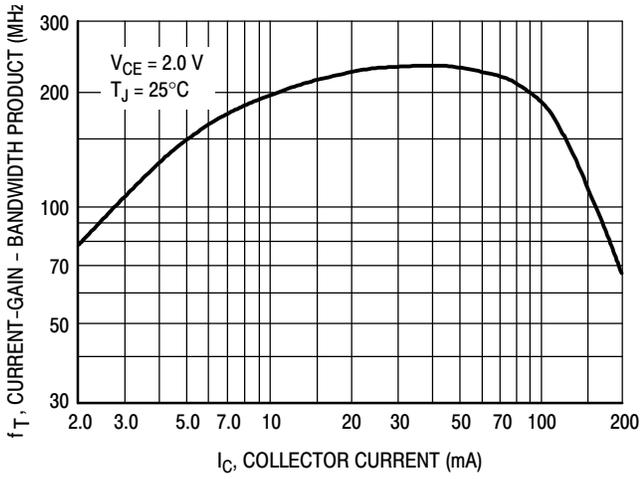


Figure 2. Current-Gain — Bandwidth Product

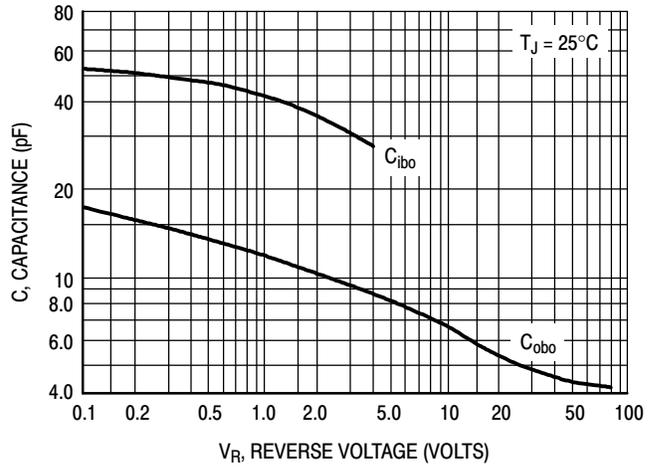


Figure 3. Capacitance

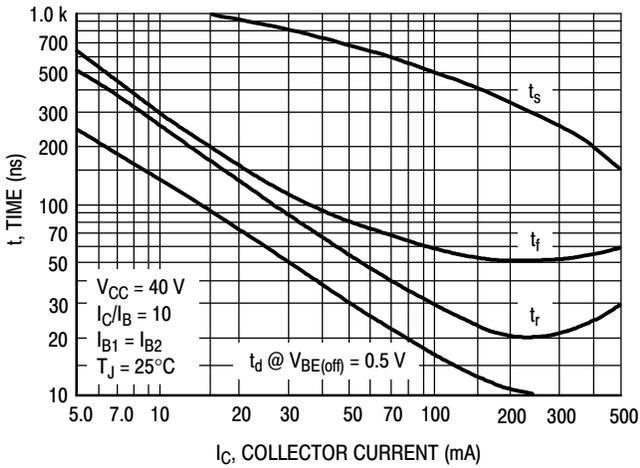


Figure 4. Switching Time

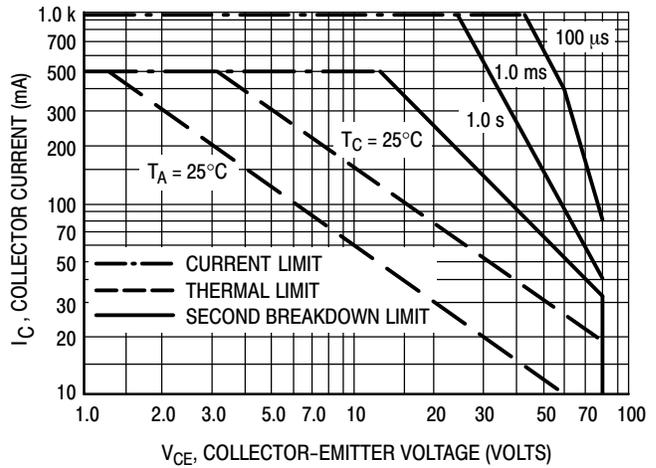


Figure 5. Active-Region Safe Operating Area

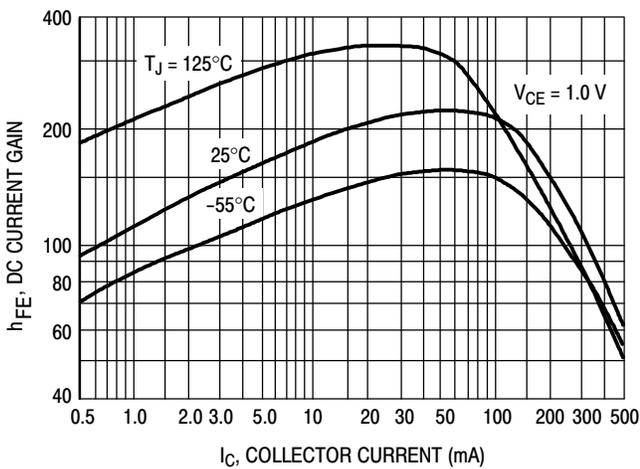


Figure 6. DC Current Gain

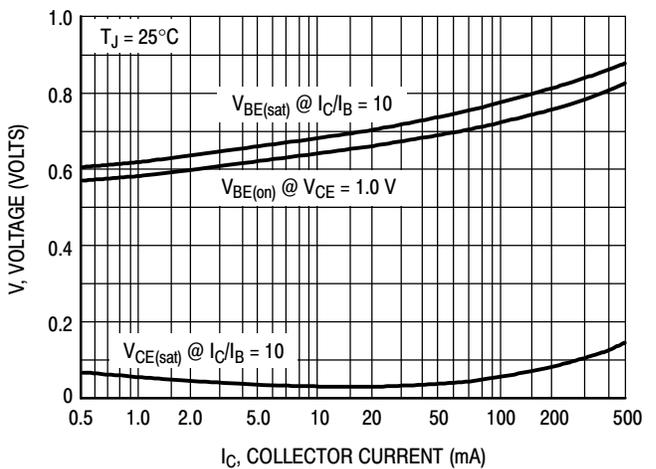


Figure 7. "ON" Voltages

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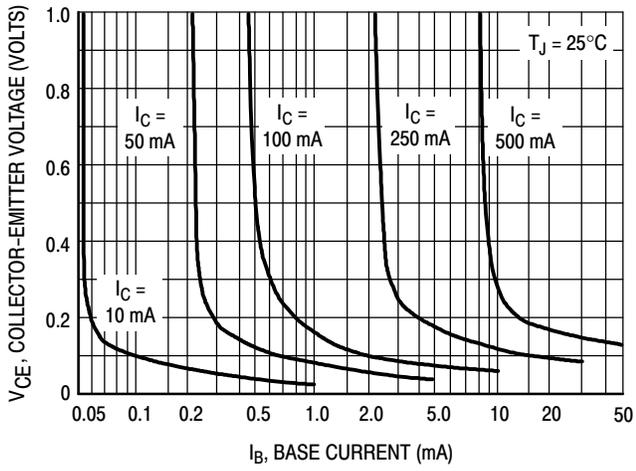


Figure 8. Collector Saturation Region

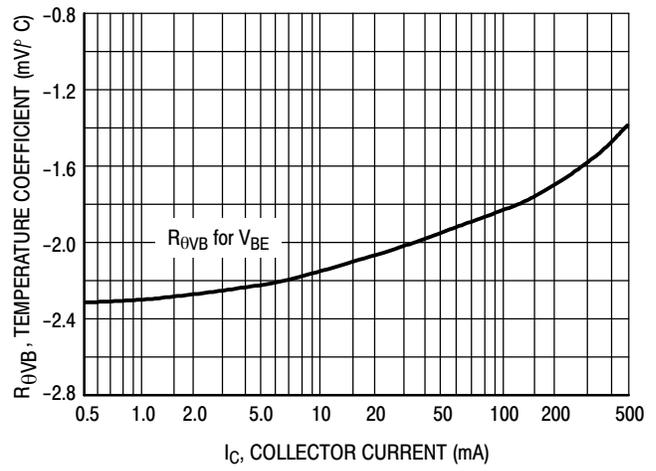
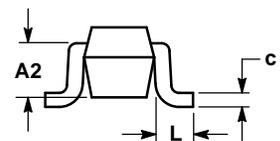
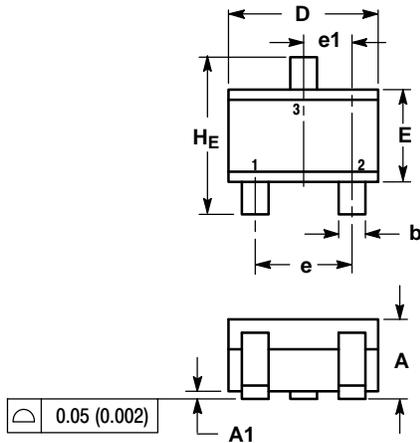


Figure 9. Base-Emitter Temperature Coefficient

MMBTA06W, SMMBTA06W,

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N

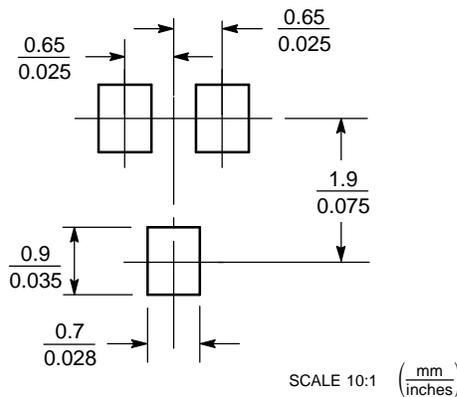


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

- STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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